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SN74LV1T126

SCLS744A - DECEMBER 2013 - REVISED FEBRUARY 2014

Support &

Community

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SN74LV1T126 Single Power Supply Single Buffer Gate with 3-State Output CMOS Logic Level Shifter

Technical

Documents

Features 1

- Single-Supply Voltage Translator at 5.0/3.3/2.5/1.8V V_{CC}
- Operating Range of 1.8V to 5.5V
- Up Translation
 - 1.2V⁽¹⁾ to 1.8V at 1.8V V_{CC}
 - 1.5V⁽¹⁾ to 2.5V at 2.5V V_{CC}
 - 1.8V⁽¹⁾ to 3.3V at 3.3V V_{CC}
 - 3.3V to 5.0V at 5.0V V_{CC}
- **Down Translation**
 - 3.3V to 1.8V at 1.8V V_{CC}
 - 3.3V to 2.5V at 2.5V V_{CC}
 - 5.0V to 3.3V at 3.3V V_{CC}
- Logic Output is Referenced to V_{CC}
- **Output Drive**
 - 8.0mA Output Drive at 5.0V
 - 7.0mA Output Drive at 3.3V
 - 3.0mA Output Drive at 1.8V
- Characterized up to 50MHz at 3.3V Vcc
- 5.0V Tolerance on Input Pins
- -40°C to 125°C Operating Temperature Range
- Latch-Up Performance Exceeds 250mA Per JESD 17
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- Supports Standard Logic Pinouts
- CMOS Output B Compatible with AUP1G and LVC1G Families
- (1) Refer to the $V_{\text{IH}}/V_{\text{IL}}$ and output drive for lower V_{CC} condition

2 Applications

Industrial controllers •

Tools &

Software

- Telecom
- Portable applications
- Servers
- PC and notebooks
- Automotive

3 Description

SN74LV1T126 is a low voltage CMOS gate logic that operates at a wider voltage range for industrial, portable, telecom, and automotive applications. The output level is referenced to the supply voltage and is able to support 1.8V/2.5V/3.3V/5V CMOS levels.

The input is designed with a lower threshold circuit to match 1.8V input logic at V_{CC} = 3.3V and can be used in 1.8V to 3.3V level up translation. In addition, the 5V tolerant input pins enable down translation (e.g. 3.3V to 2.5V output at V_{CC} = 2.5V). The wide V_{CC} range of 1.8V to 5.5V allows generation of desired output levels to connect to controllers or processors.

The SN74LV1T126 is designed with current-drive capability of 8 mA to reduce line reflections, overshoot, and undershoot caused by high-drive outputs.

Device Information

ORDER NUMBER	PACKAGE	BODY SIZE
SN74LV1T126DBVR	SOT-23 (5)	2,90mm x 1,60mm
SN74LV1T126DCKR	SC70 (5)	2,00mm x 1,25mm

DCK or DBV PACKAGE (TOP VIEW)

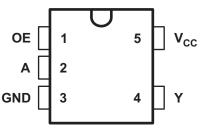


Table of Contents

- 1 Features 1 2 Applications1 3 Description1 4
 - Revision History 2
 - 4.1 Logic Diagram 3 4.2 Typical Design Examples 5
 - 4.3 Absolute Maximum Ratings 6
 - 4.4 Recommended Operating Conditions 6

	4.6	Switching Characteristics 8
	4.7	Operating Characteristics 8
5	Para	ameter Measurement Information
	5.1	More Product Selection 10
6	Dev	ice and Documentation Support 11
	6.1	Trademarks 11
	6.2	Electrostatic Discharge Caution 11
	6.3	Glossary 11
7		hanical, Packaging, and Orderable rmation

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

CI	hanges from Original (December 2013) to Revision A	Page	e
•	Updated document formatting.		1

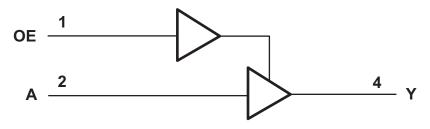
INPU (Lower Leve	OUTPUT (V _{CC} CMOS)	
OE ⁽¹⁾	А	Y
Н	Н	Н
Н	L	L
L	Х	Z

Function Table

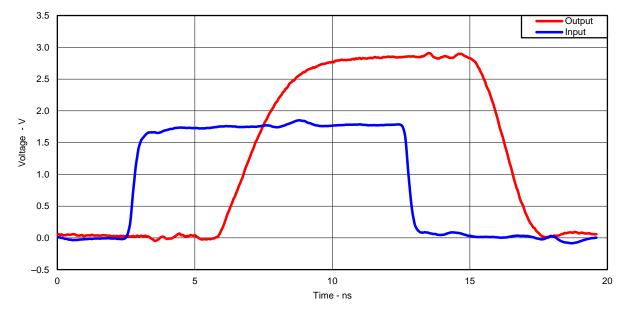
(1) Not recommend to floating OE pin for signal oscillation

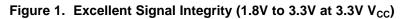
SUPPLY Vcc = 3.3V					
INPU (Lower Leve	OUTPUT (V _{CC} CMOS)				
А	В	Y			
VIH(min) = VIL(max) =		VOH(min) = 2.9 V VOL(max)= 0.2 V			

4.1 Logic Diagram



Switching Characteristics at 50 MHz





Logic Diagram (continued)

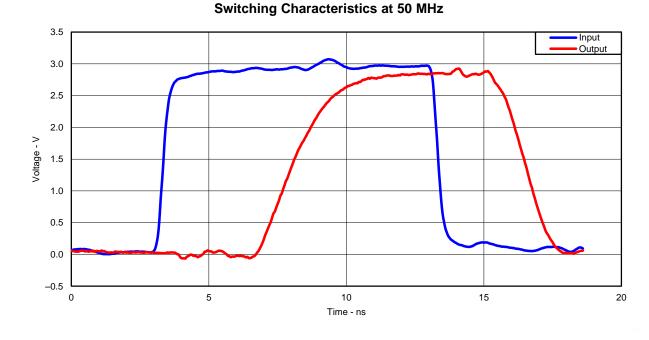
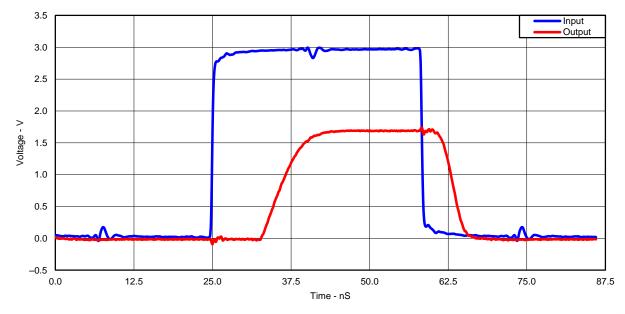


Figure 2. Excellent Signal Integrity (3.3V to 3.3V at 3.3V V_{cc})



Switching Characteristics at 15 MHz

Figure 3. Excellent Signal Integrity (3.3V to 1.8V at 1.8V $V_{\text{CC}})$



4.2 Typical Design Examples

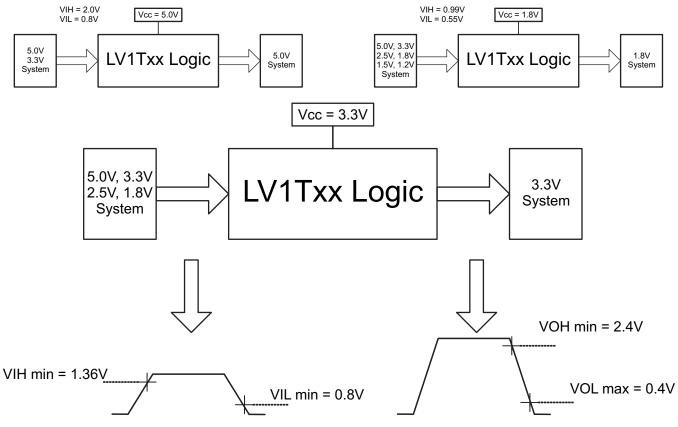


Figure 4. Switching Thresholds for 1.8-V to 3.3-V Translation

4.3 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	7.0	V
VI	Input voltage range ⁽²⁾	-0.5	7.0	V	
v	Voltage range applied to	-0.5	4.6	V	
Vo	Voltage range applied to	any output in the high or low state ⁽²⁾	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-20	mA
I _{OK}	Output clamp current	$V_{O} < 0 \text{ or } V_{O} > V_{CC}$		±20	mA
I _O	Continuous output curren	t		±25	mA
	Continuous current throug	gh V _{CC} or GND		±50	mA
0	Package thermal	DBV package		206	°C/W
θ_{JA}	impedance ⁽³⁾	DCK package		252	C/W
T _{stg}	Storage temperature rang	Storage temperature range			

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The package thermal impedance is calculated in accordance with JESD 51-7.

4.4 Recommended Operating Conditions⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage		1.6	5.5	V
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 1.8 V		-3.0	
	High-level output	$V_{CC} = 2.5 V$		-5.0	~ ^
I _{OH}	current	$V_{CC} = 3.3 V$		-7.0	mA
		$V_{CC} = 5.0 V$		-8.0	
		V _{CC} = 1.8 V		3.0	
	Low-level output	$V_{CC} = 2.5 V$		5.0	0
I _{OL}	current	$V_{CC} = 3.3 V$		7.0	mA
		V _{CC} = 5.0 V		8.0	
		V _{CC} = 1.8 V		20	
Δt/Δv	t/Δv Input transition rise or fall rate	V _{CC} = 3.3 V or 2.5 V		20	ns/V
		$V_{CC} = 5.0 V$		20	
T _A	Operating free-air temp	perature	-40	125	°C

(1) All unused inputs of the device must be held at VCC or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



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4.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

DADAMETER		TEST CONDITIONS		T _A = 25°C			$T_A = -40^{\circ}C to$		
	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	MIN	MAX	UNIT
			$V_{CC} = 1.65 \text{ V to } 1.8 \text{ V}$	0.95			1.0		
			V _{CC} = 2.0 V	0.99			1.03		
			V_{CC} = 2.25 V to 2.5 V	1.145			1.18		
V	High-level input		V _{CC} = 2.75 V	1.22			1.25		N
VIH	voltage		_{VCC} = 3.0 V to 3.3 V	1.37			1.39		V
			V _{CC} = 3.6 V	1.47			1.48		
			$V_{CC} = 4.5 \text{ V to } 5.0 \text{ V}$	2.02			2.03		
			V _{CC} = 5.5 V	2.1			2.11		
			$V_{CC} = 1.65 \text{ V to } 2.0 \text{ V}$			0.57		0.55	
.,	Low-level input		V_{CC} = 2.25 V to 2.75 V			0.75		0.71	
VIL	voltage		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$			0.8		0.65	V
			$V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$			0.8		0.8	
		I _{OH} = -20 μA	1.65 V to 5.5 V	V _{CC} – 0.1			V _{CC} – 0.1		
			1.65 V	1.28			1.21		
		$I_{OH} = -2.0 \text{ mA}$	1.8 V	1.5			1.45		V
		I _{OH} = -3.0 mA	2.3 V	2.0			1.93		
		$I_{OH} = -3.0 \text{ mA}$	2.5 V	2.25			2.15		
V _{OH}		$I_{OH} = -3.0 \text{ mA}$		2.78			2.7		
- OH		$I_{OH} = -5.5 \text{ mA}$	- 3.0 V	2.6			2.49		
		I _{OH} = -5.5 mA	3.3 V	2.9			2.8		
		$I_{OH} = -4.0 \text{ mA}$		4.2			4.1		V
		$I_{OH} = -8.0 \text{ mA}$	4.5 V	4.1			3.95		
		$I_{OH} = -8.0 \text{ mA}$	5.0 V	4.6			4.5		
		$I_{OL} = 20.0 \ \mu A$	1.65 V to 5.5 V			0.1		0.1	
		$I_{OL} = 2.0 \text{ mA}$	1.65 V			0.2		0.25	
		$I_{OH} = 3.0 \text{ mA}$	2.3 V			0.15		0.2	
V _{OL}		$I_{OL} = 3.0 \text{ mA}$	2.0 1			0.11		0.15	v
♥0L		$I_{OL} = 5.5 \text{ mA}$	- 3.0 V			0.21		0.252	·
		$I_{OL} = 4.0 \text{ mA}$				0.15		0.202	
		$I_{OL} = 8.0 \text{ mA}$	– 4.5 V			0.13		0.35	
			0 V, 1.8 V, 2.5 V, 3.3 V,			0.5		0.55	
l _l	A input	$V_I = 0 V \text{ or } V_{CC}$	5.5 V			0.1		±1.0	μA
			5.0 V			1.0		10.0	
		$V_{I} = 0 V \text{ or } V_{CC}; I_{O} = 0;$	3.3 V			1.0		10.0	
I _{CC}		Open on loading	2.5 V			1.0		10.0	μA
		-	1.8 V			1.0		10.0	
		One input at 0.3 V or 3.4 V Other inputs at 0 or V_{CC} , $I_0 = 0$	5.5 V			1.35		1.5	mA
∆I _{CC}		One input at 0.3 V or 1.1 V Other inputs at 0 or V _{CC} , $I_0 = 0$	1.8 V			10.0		10.0	μA
Ci		$V_{I} = V_{CC}$ or GND	3.3 V		2.0	10.0	2.0	10.0	pF
Co		$V_0 = V_{CC}$ or GND	3.3 V		2.5		2.5		pF

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4.6 Switching Characteristics

	FROM	то	FREQUENCY	V	,	T _A :	= 25°C	;	T _A = -65°	C to 1	25°C	UNIT																		
PARAMETER	(INPUT)	(OUTPUT)	(TYP)	V _{cc}	CL	MIN	ТҮР	MAX	MIN	ТҮР	MAX	UNIT																		
				5.0 V	15 pF		2.7	5.5		3.4	6.5																			
			DC to 50 MHz		30 pF		3.0	6.5		4.1	7.5	ns																		
			DC 10 50 MHZ	3.3 V	15 pF		4.0	7.0		5.0	8.0	ns																		
t	Any In	Y		5.5 V	30 pF		4.9	8.0		6.0	9.0	115																		
t _{pd}			DC to 25 MHz	2.5 V	15 pF		5.8	8.5		6.8	9.5	ns																		
				2.3 V	30 pF		6.5	9.5		7.5	10.5	115																		
			DC to 15 MHz	DC to 15 MHz 1.8 V	15 pF		10.5	13.0		11.8	14.0	ns																		
			DO 10 13 WHZ	1.0 V	30 pF		12.0	14.5		12.0	15.5	113																		
			DC to 50 MHz 5.0 V 3.3 V DC to 25 MHz 2.5 V	5 0 V	15 pF		3.0	5.0		3.5	6.0	ns																		
											DC to 50 MHz	DC to 50 MHz	DC to 50 MHz	DC to 50 MHz	DC to 50 MHz	0.0 V	30 pF		4.3	6.5		4.9	7.5	113						
																						DO 10 00 Mil 12	33V	15 pF		4.0	6.5		4.5	7.5
t _{PZH} , t _{PZL}	OE	Y									5.5 V	30 pF		5.0	8.0		6.5	9.0	113											
ΨZH, ΨZL	OL										DC to 25 MHz	25.V	15 pF		5.5	8.0		6.1	9.0	ns										
																	- 5 10 20 11112			2.5 V	30 pF		7.0	10.0		8.5	11.0	115		
			DC to 15 MHz	1.8 V	15 pF		9.0	12.0		9.85	13.0	ns																		
			DO 10 10 10112	1.0 V	30 pF		12.5	15.0		13.5	16.0	115																		
				5.0 V	15 pF		4.2	6.5		4.5	7.0	ns																		
			DC to 50 MHz	0.0 V	30 pF		4.8	8.0		5.0	8.5	115																		
			DO 10 30 MI 12	3.3 V	15 pF		4.5	7.0		5.0	8.0	ns																		
t _{PHZ} , t _{PLZ}	OE	Y		0.0 V	30 pF		5.0	8.0		5.5	9.0	115																		
YHZ, YLZ		2.5 V	15 pF		5.0	11.0		6.0	9.0	ns																				
		DC 10 2									2.5 V	30 pF		6.0	9.0		7.0	10.0	113											
			DC to 15MHz	1.8 V	15 pF		8.0	10.0		8.5	11.0	ns																		
				1.0 V	30 pF		8.5	11.0		9.5	12.0	115																		

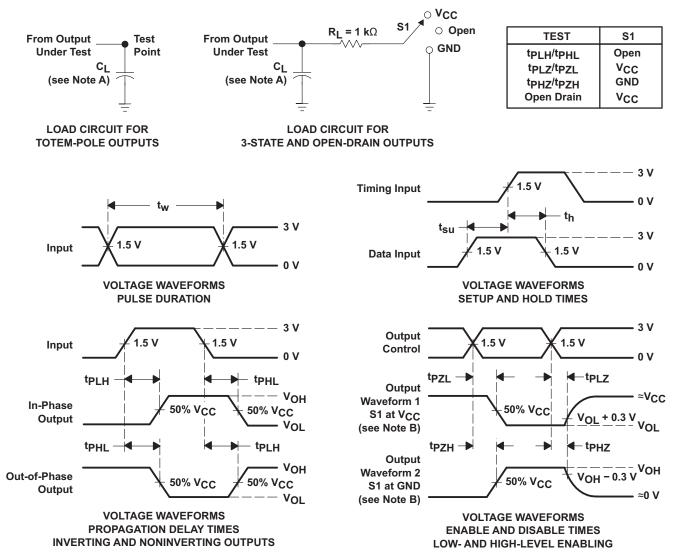
4.7 Operating Characteristics

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{cc}	TYP	UNIT
			1.8 V ± 0.15 V	14	
		2.5 V ± 0.2 V	14		
C _{pd}	C _{pd} Power dissipation capacitance	f = 1 MHz and 10 MHz	3.3 V ± 0.3 V	14	pF
			5.0 V ± 0.5 V	14	



5 Parameter Measurement Information



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_r \leq 3 ns, t_f \leq 3 ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 5. Load Circuit and Voltage Waveforms

Parameter Measurement Information (continued)

5.1 More Product Selection

DEVICE	PACKAGE	DESCRIPTION
SN74LV1T00	DCK, DBV	2-Input Positive-NAND Gate
SN74LV1T02	DCK, DBV	2-Input Positive-NOR Gate
SN74LV1T04	DCK, DBV	Inverter Gate
SN74LV1T08	DCK, DBV	2-Input Positive-AND Gate
SN74LV1T126	DCK, DBV, DPW	Single Buffer Gate
SN74LV1T14	DCK, DBV	Single Schmitt-Trigger Inverter Gate
SN74LV1T32	DCK, DBV	2-Input Positive-OR Gate
SN74LV1T86	DCK, DBV	Single 2-Input Exclusive-Or Gate
SN74LV1T125	DCK, DBV	Single Buffer Gate with 3-state Output
SN74LV1T126	DCK, DBV	Single Buffer Gate with 3-state Output
SN74LV4T125	RGY, PW	Quadruple Bus Buffer Gate With 3-State Outputs



6 Device and Documentation Support

6.1 Trademarks

All trademarks are the property of their respective owners.

6.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms and definitions.

7 Mechanical, Packaging, and Orderable Information

The following packaging information and addendum reflect the most current data available for the designated devices. This data is subject to change without notice and revision of this document.



10-Jul-2018

PACKAGING INFORMATION

Orderable Device	Status	Package Type		Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74LV1T126DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(NEN3, NENS)	Samples
SN74LV1T126DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	NEN3	Samples
SN74LV1T126DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 125	(WN3, WNS)	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

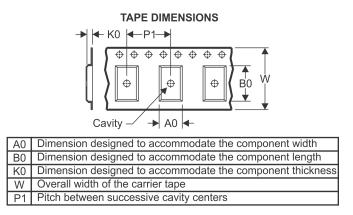
PACKAGE MATERIALS INFORMATION

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Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV1T126DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74LV1T126DBVR	SOT-23	DBV	5	3000	178.0	9.2	3.3	3.23	1.55	4.0	8.0	Q3
SN74LV1T126DBVRG4	SOT-23	DBV	5	3000	178.0	9.2	3.3	3.23	1.55	4.0	8.0	Q3
SN74LV1T126DCKR	SC70	DCK	5	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LV1T126DCKR	SC70	DCK	5	3000	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

29-May-2018



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV1T126DBVR	SOT-23	DBV	5	3000	202.0	201.0	28.0
SN74LV1T126DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74LV1T126DBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74LV1T126DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
SN74LV1T126DCKR	SC70	DCK	5	3000	202.0	201.0	28.0

DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AA.



LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DBV 5

GENERIC PACKAGE VIEW

SOT-23 - 1.45 mm max height SMALL OUTLINE TRANSISTOR



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC MO-178.



EXAMPLE BOARD LAYOUT

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.

5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



EXAMPLE STENCIL DESIGN

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

7. Board assembly site may have different recommendations for stencil design.



^{6.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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SOT-23 - 1.45 mm max height

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